imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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FAIRCHILD

SEMICONDUCTOR IM

BDW23/A/B/C

Hammer Drivers, Audio Amplifiers Applications

Power Darlington TR

• Complement to BDW24, BDW24A, BDW24B and BDW24C respectively



1.Base 2.Collector 3.Emitter

NPN Epitaxial Silicon Transistor

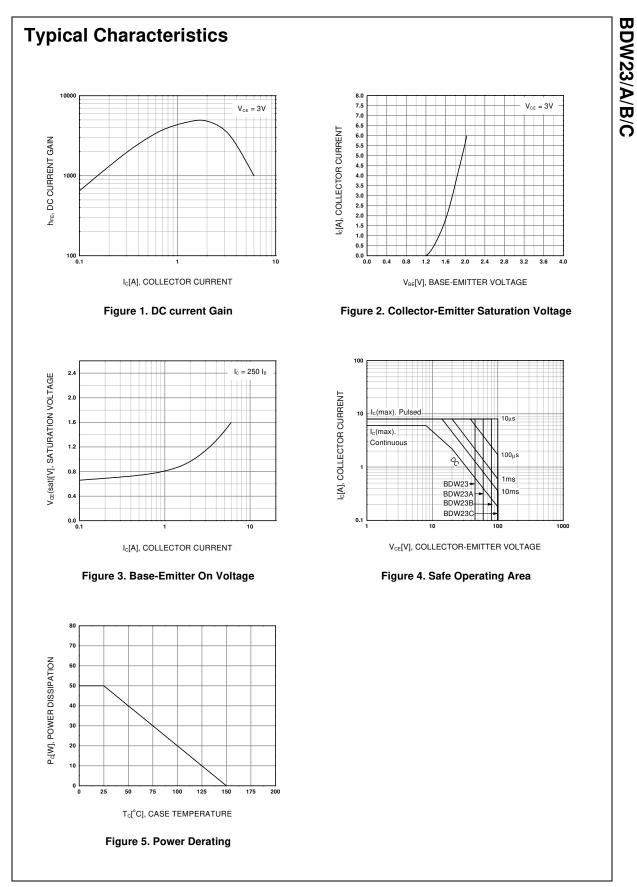
Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage		
	: BDW23	45	V
	: BDW23A	60	V
	: BDW23B	80	V
	: BDW23C	100	V
V _{CEO}	Collector-Emitter Voltage		
	: BDW23	45	V
	: BDW23A	60	V
	: BDW23B	80	V
	: BDW23C	100	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	6	А
I _{CP}	*Collector Current (Pulse)	8	А
I _B	Base Current	0.2	А
P _C	Collector Dissipation (T _C =25°C)	50	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 150	°C

BDW23/A/B/C

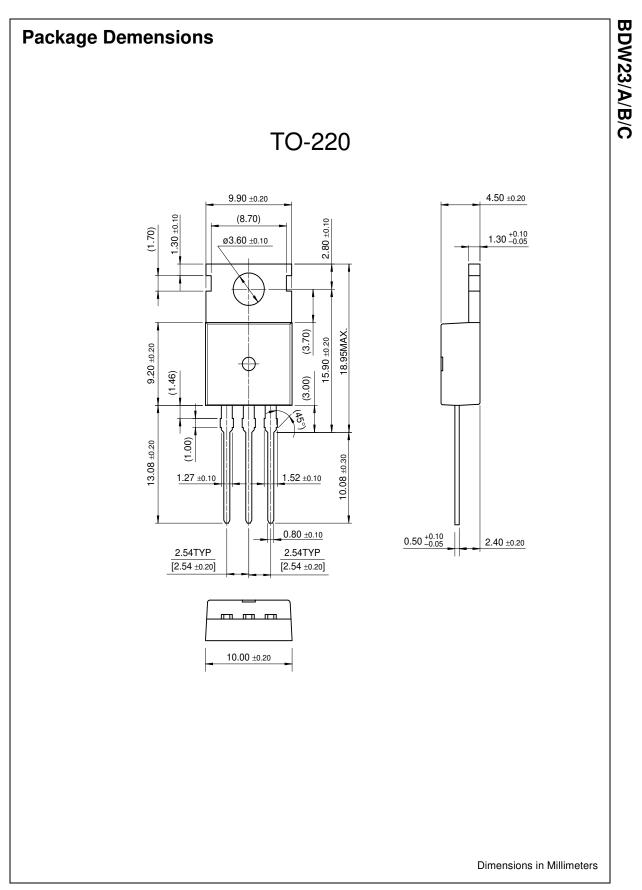
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit s
V _{CEO} (sus)	Collector-Emitter Sustaining Voltage : BDW23 : BDW23A : BDW23B : BDW23C	I _C = 100mA, I _B = 0	45 60 80 100			V V V V
СВО	Collector Cut-off Current : BDW23 : BDW23A : BDW23B : BDW23B	$V_{CB} = 45V, I_E = 0$ $V_{CB} = 60V, I_E = 0$ $V_{CB} = 80V, I_E = 0$ $V_{CB} = 100V, I_E = 0$			200 200 200 200	μΑ μΑ μΑ μΑ
ICEO	Collector Cut-off Current : BDW23 : BDW23A : BDW23B : BDW23C	$V_{CE} = 22V, I_{B} = 0$ $V_{CE} = 30V, I_{B} = 0$ $V_{CE} = 40V, I_{B} = 0$ $V_{CE} = 50V, I_{B} = 0$			500 500 500 500	μΑ μΑ μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			2	mA
h _{FE}	* DC Current Gain	$V_{CE} = 3V, I_C = 1A$ $V_{CE} = 3V, I_C = 2A$ $V_{CE} = 3V, I_C = 6A$	1000 750 100		20000	
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	$I_{C} = 2A, I_{B} = 8mA$ $I_{C} = 6A, I_{B} = 60mA$			2 3	V V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	I _C = 2A, I _B = 8mA			2.5	V
V _{BE} (on)	* Base-Emitter ON Voltage	$V_{CE} = 3V, I_C = 1A$ $V_{CE} = 3V, I_C = 6A$			2.5 3	V V
VF	* Parallel Diode Forward Voltage	I _F = 2A			1.8	V

BDW23/A/B/C



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Rev. A, February 2000



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Definition of Terms

Datasheet Identification	Product Status	Definition
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